Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-088-3951

Inclosure Material:	
Glass	
Overall Length:	
Between 0.230 inches and 0.300 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.085 inches and 0.107 inches	
End Application:	
Central message switch, an/tyc-39v; compressor, reciprocating m5	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
Do-7	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
20.0 reverse breakdown voltage, dc	
Current Rating Per Characteristic:	
200.00 milliamperes source cutoff current preset	
Power Rating Per Characteristic:	
250.0 milliwatts small-signal input power, common-collector absolute	
Maximum Operating Tempurature Per Measurement Point:	
125.0 degrees celsius junction	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	